

Technical Data Data Sheet N1177, Rev. - **Green Products**

189NQ135/R-1 189NQ150/R-1 SCHOTTKY RECTIFIER

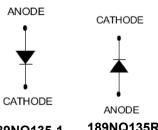
Applications:

• Switching power supply • Converters • Free-Wheeling diodes • Reverse battery protection

Features:

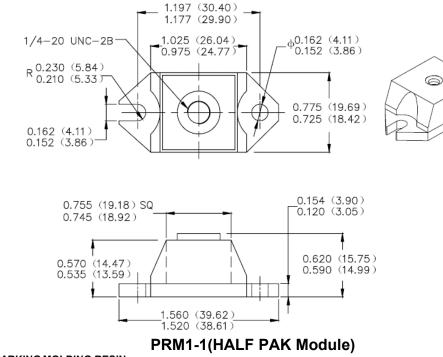
- 175℃ T_J operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5'S
- Easier to mount and lower profile than DO-5'S
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In Inches / mm





189NQ135R-1



MARKING,MOLDING RESIN Marking for 189NQ135/R-1, 1st row SS YYWWL, 2nd row 189NQ135/R-1 Where YY is the manufacture year WW is the manufacture week code L is the wafer's Lot Number Molding resin Epoxy resin UL:94V-0



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Maximum Ratings:

Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V _{RWM}	-	135 189NQ135/R-1		V
			150	189NQ150/R-1	
Max. Average Forward Current	I _{F(AV)}	50% duty cycle @T _c =110°C, rectangular wave form	180		A
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	2130		A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	V_{F1}	 @ 180A, Pulse, T_J = 25 °C @ 360A, Pulse, T_J = 25 °C 	1.07 1.27	V
	V_{F2}	@ 180A, Pulse, T _J = 125 °C @ 360A, Pulse, T _J = 125 °C	0.74 0.86	V
Max. Reverse Current (per	I _{R1}	$@V_R = rated V_R T_J = 25 °C$	4.5	mA
leg) *	I _{R2}	$@V_R = rated V_R T_J = 125 °C$	65	mA
Max. Junction Capacitance (per leg)	C _T	$@V_R = 5V, T_C = 25 \degree C$ $f_{SIG} = 1MHz$	4500	pF
Typical Series Inductance (per leg)	Ls	Measured lead to lead 5 mm from package body	6.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

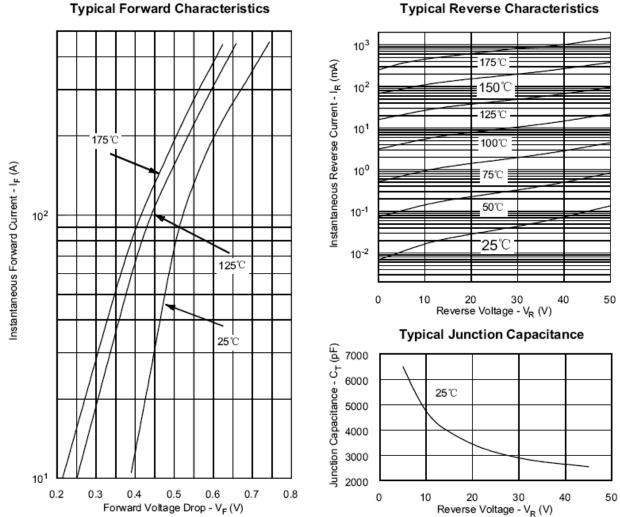
• Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	_ Specific	Units		
Max. Junction Temperature	TJ	-	-55 to -	°C		
Max. Storage Temperature	T _{stg}	-	-55 to +175		°C	
Maximum Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.30		°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ ext{ heta}cs}$	Mounting surface, smooth and greased	0.15		°C/W	
Mounting Torque	Тм	Non-lubricated threads	Mounting Torque Terminal	23(min) 29(max) 35(min)	Kg-cm	
			Torque	46(max)		
Approximate Weight	wt	-	25.	g		
Case Style	PRM1-1					



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Typical Reverse Characteristics

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